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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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DATA SHEET



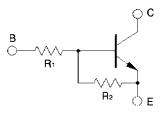
Phase-out/Discontinued BB1 SERIES

on-chip resistor NPN silicon epitaxial transistor For mid-speed switching

The BB1 Series is an N type small signal transistor and enables the reduction of component counts and downsizing of sets due to on-chip resistors. This transistor is especially ideal for use in household electronic appliances and OA equipments such as VCRs and TVs.

FEATURES

- Up to 0.7 A current drive available
- On-chip bias resistor
- · Low power consumption during drive

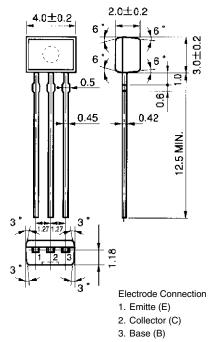


QUALITY GRADES

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

PACKAGE DRAWING (UNIT: mm)



BB1 SERIES LISTS

Products	R1 (KΩ)	R₂ (KΩ)
BB1A4A	_	10
BB1L2Q	0.47	4.7
BB1A3M	1.0	1.0
BB1F3P	2.2	10
BB1J3P	3.3	10
BB1L3N	4.7	10
BB1A4M	10	10

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Phase-out/Discontinued

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base volgate	Vсво	30	V
Colletor to emitter voltage	VCEO	25	V
Emitter to base voltage	VEBO	10	V
Collector current (DC)	IC(DC)	0.7	А
Collector current (Pulse)	C(pulse) Note 1	1.0	А
Base current (DC)	B(DC)	0.02	А
Total power dissipation	Р⊤	250	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note 1 PW \leq 10 ms, duty cycle \leq 50 %

BB1A4A

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 30 V, IE = 0			100	nA
DC current gain	hfE1 ^{Note 2}	Vce = 2.0 V, Ic = 0.1 A	300			-
DC current gain	hfe2 ^{Note 2}	Vce = 2.0 V, Ic = 0.5 A	300			-
DC current gain	hfe3 ^{Note 2}	Vce = 2.0 V, Ic = 0.7 A	135			-
Collector saturation voltage	VCE(sat) Note 2	Ic = 0.5 A, Iв = 5 mA		0.27	0.4	V
Low level input voltage	VIL ^{Note 2}	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$			0.3	V
Input resistance	R1		-	-	-	Ω
E-to-B resistance	R2		7	10	13	kΩ

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1L2Q ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0$			100	nA
DC current gain	hFE1 Note 2	Vce = 2.0 V, Ic = 0.1 A	150	400		-
DC current gain	hFE2 Note 2	Vce = 2.0 V, Ic = 0.5 A	300	700		-
DC current gain	hfe3 ^{Note 2}	Vce = 2.0 V, Ic = 0.7 A	135	600		-
Low level output voltage	VOL ^{Note 2}	V _{IN} = 5.0 V, Ic = 0.5 A		0.2	0.3	V
Low level input voltage	VIL ^{Note 2}	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$			0.3	V
Input resistance	R1		329	470	611	Ω
E-to-B resistance	R2		3.29	4.7	6.11	kΩ

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1A3M ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	V _{CB} = 30 V, I _E = 0			100	nA
DC current gain	hFE1 ^{Note 2}	Vce = 2.0 V, Ic = 0.1 A	80			-
DC current gain	hFE2 ^{Note 2}	Vce = 2.0 V, Ic = 0.5 A	100			-
DC current gain	hFE3 ^{Note 2}	Vce = 2.0 V, Ic = 0.7 A	135			-
Low level output voltage	VOL Note 2	V _{IN} = 5.0 V, Ic = 0.5 A		0.3	0.4	V
Low level input voltage	VIL ^{Note 2}	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$			0.3	V
Input resistance	R1		0.7	1.0	1.3	kΩ
E-to-B resistance	R2		0.7	1.0	1.3	kΩ

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1F3P

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0$			100	nA
DC current gain	hfe1 ^{Note 2}	Vce = 2.0 V, lc = 0.1 A	300			-
DC current gain	hFE2 Note 2	Vce = 2.0 V, Ic = 0.5 A	300			-
DC current gain	hfe3 ^{Note 2}	Vce = 2.0 V, Ic = 0.7 A	135			-
Low level output voltage	VOL ^{Note 2}	V _{IN} = 5.0 V, Ic = 0.3 A			0.3	V
Low level input voltage	VIL ^{Note 2}	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$			0.3	V
Input resistance	Rı		1.54	2.2	2.86	kΩ
E-to-B resistance	R2		7	10	13	kΩ

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BP1J3P

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 30 V, I_E = 0$			100	nA
DC current gain	hfE1 Note 2	Vce = 2.0 V, Ic = 0.1 A	300	600		_
DC current gain	hfe2 ^{Note 2}	Vce = 2.0 V, Ic = 0.5 A	300	700		-
DC current gain	hfe3 ^{Note 2}	Vce = 2.0 V, Ic = 0.7 A	135	600		_
Low level output voltage	VOL ^{Note 2}	$V_{IN} = 5.0 V$, Ic = 0.2 A		0.14	0.3	V
Low level input voltage	VIL ^{Note 2}	Vcε = 5.0 V, lc = 100 μA			0.3	V
Input resistance	R1		2.31	3.3	4.29	kΩ
E-to-B resistance	R2		7	10	13	kΩ

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1L3N ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 30 V, I_E = 0$			100	nA
DC current gain	hfE1 ^{Note 2}	Vce = 2.0 V, Ic = 0.1 A	300			-
DC current gain	hfe2 ^{Note 2}	Vce = 2.0 V, Ic = 0.5 A	300			-
DC current gain	hfe3 ^{Note 2}	Vce = 2.0 V, Ic = 0.7 A	135			_
Low level output voltage	VOL Note 2	V _{IN} = 5.0 V, Ic = 0.2 A			0.3	V
Low level input voltage	VIL ^{Note 2}	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$			0.3	V
Input resistance	Rı		3.29	4.7	6.11	kΩ
E-to-B resistance	R2		7	10	13	kΩ

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

BB1A4M

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0$			100	nA
DC current gain	hfe1 ^{Note 2}	Vce = 2.0 V, Ic = 0.1 A	300			-
DC current gain	hFE2 ^{Note 2}	Vce = 2.0 V, Ic = 0.5 A	300			_
DC current gain	hfe3 ^{Note 2}	Vce = 2.0 V, Ic = 0.7 A	135			-
Collector saturation voltage	VOL ^{Note 2}	V _{IN} = 5.0 V, Ic = 0.2 A			0.3	V
Low level input voltage	VIL Note 2	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$			0.3	V
Input resistance	R1		7	10	13	kΩ
E-to-B resistance	R₂		7	10	13	kΩ

Note 2 PW \leq 350 μ s, duty cycle \leq 2 %

 $R_1 = 470 \Omega$

0.8

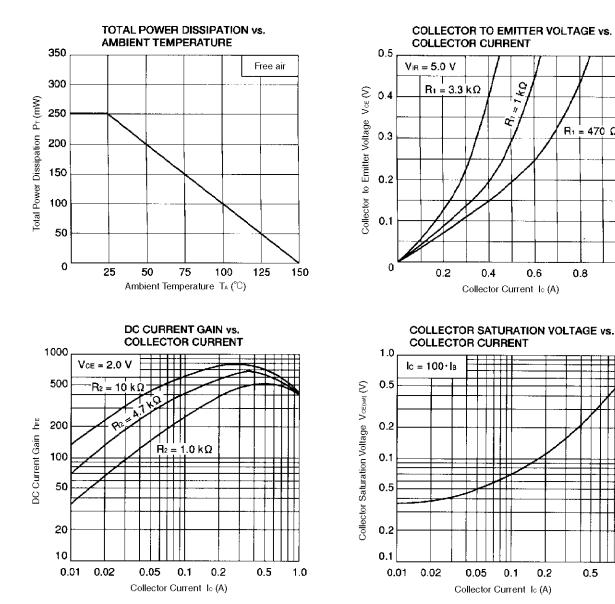
0.5

1.0

1.0

Phase-out/Discontinued

TYPICAL CHARACTERISTICS (Ta = 25°C)



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